

# Lattice dynamical implication of ilmenite $MgXO_3$ ( $X=Si, Ge, Ti$ ) using Raman spectroscopy at high-pressures and high-temperatures

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Ilmenite-type  $MgX_4O_3$  have various stable P-T region due to their composition:  $MgSiO_3$ -,  $MgGeO_3$ - and  $MgTiO_3$ -ilmenite is stable at high-pressures, moderate-pressures and ambient pressure, respectively. In this study, we conducted a high-pressure, high-temperature Raman spectroscopic study of ilmenite-type  $MgSiO_3$ ,  $MgGeO_3$  and  $MgTiO_3$ . From the viewpoint of elasticity and bonding energy, we investigate the behavior of ilmenite at high-pressure and high-temperature and compare structures of ilmenites that have different compositions.

Raman spectroscopy was a triple microspectrometer equipped with an optical microscope and an Ar ion laser. High-temperature experiments were performed using a Pt-electric resistant heater. For the high-pressure experiments, a diamond-anvil cell (DAC) was used using  $H_2O$  as the pressure media. Raman spectra of each sample were collected up to 770 K at ambient pressure and 30 GPa at room temperature, respectively.

From the obtained Raman bands, we calculated the force constant,  $k$ , of the stretching mode ( $A_g(1)$  and  $E_g(1)$ ) and obtained the temperature and pressure dependence of  $k$ . The temperature dependence of  $k$  was the order of Ge-O, Si-O and Ti-O stretching bands. The tendency induces the relative expansion rate for each  $XO_6$  ( $X=Si, Ge, Ti$ ) octahedron. This is consistent with the fact that  $MgTiO_3$  ilmenite is the only stable phase phase at the present HT experimental conditions. On the other hand, the order of the pressure dependence of  $k$  is complex. For Si-O and Ge-O bonds, the pressure dependence of  $k$  of  $A_g(1)$  is larger than that of  $E_g(1)$ . Namely, shorter X-O bonds ( $A_g(1)$ ) are more shortened under pressure than longer X-O bonds ( $E_g(1)$ ), indicating that the distortion of  $XO_6$  octahedra is enhanced at higher pressures. For Ti-O bond, the contrary pressure dependence was observed. These phenomena obtained are consistent with the results of the single-crystal structure analyses by Yamanaka et al. (2003, submitted).